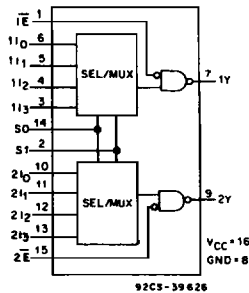


Advance Information



**FUNCTIONAL DIAGRAM**

## Dual 4-Input Multiplexer

**Type Features:**

- Buffered inputs
- Typical propagation delay:  
6.3 ns @  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{ C}$ ,  $C_L = 50\text{ pF}$

The RCA CD54/74AC153 and CD54/74ACT153 dual 4-input multiplexers use the RCA ADVANCED CMOS technology. One of the four sources for each section is selected by the common Select inputs, S0 and S1. When the Enable inputs ( $\overline{1E}$ ,  $\overline{2E}$ ) are HIGH, the outputs are in the low state.

The CD74AC153 and CD74ACT153 are supplied in 16-lead dual-in-line plastic packages (E suffix) and in 16-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC153 and CD54ACT153, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

**Family Features:**

- Exceeds 2-kV ESD Protection - MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST\*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- $\pm 24\text{-mA}$  output drive current
  - Fanout to 15 FAST\* ICs
  - Drives 50-ohm transmission lines

\*FAST is a Registered Trademark of Fairchild Semiconductor Corp.

**TRUTH TABLE**

SELECT INPUTS		DATA INPUTS				ENABLE INPUTS	OUTPUT
S1	S0	$n_i_0$	$n_i_1$	$n_i_2$	$n_i_3$	$\overline{nE}$	$nY$
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Select inputs S1 and S0 are common to both sections.

- H = High level
- L = Low level
- X = Don't care
- Z = High impedance

# CD54/74AC153

## CD54/74ACT153

**MAXIMUM RATINGS, Absolute-Maximum Values:**

DC SUPPLY-VOLTAGE ( $V_{CC}$ )	-0.5 to 6 V
DC INPUT DIODE CURRENT, $I_{IK}$ (for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V)	$\pm 20$ mA
DC OUTPUT DIODE CURRENT, $I_{OK}$ (for $V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V)	$\pm 50$ mA
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, $I_O$ (for $V_O > -0.5$ V or $V_O < V_{CC} + 0.5$ V)	$\pm 50$ mA
DC $V_{CC}$ or GROUND CURRENT ( $I_{CC}$ or $I_{GND}$ )	$\pm 100$ mA*
POWER DISSIPATION PER PACKAGE ( $P_D$ ):	
For $T_A = -55$ to $+100^\circ\text{C}$ (PACKAGE TYPE E)	500 mW
For $T_A = +100$ to $+125^\circ\text{C}$ (PACKAGE TYPE E)	Derate Linearly at $8\text{ mW}/^\circ\text{C}$ to 300 mW
For $T_A = -55$ to $+70^\circ\text{C}$ (PACKAGE TYPE M)	400 mW
For $T_A = +70$ to $+125^\circ\text{C}$ (PACKAGE TYPE M)	Derate Linearly at $6\text{ mW}/^\circ\text{C}$ to 70 mW
OPERATING-TEMPERATURE RANGE ( $T_A$ )	-55 to $+125^\circ\text{C}$
STORAGE TEMPERATURE ( $T_{stg}$ )	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. ( $1.59 \pm 0.79$ mm) from case for 10 s maximum	$+265^\circ\text{C}$
Unit inserted into PC board min. thickness $1/16$ in. ( $1.59$ mm) with solder contacting lead tips only	$+300^\circ\text{C}$

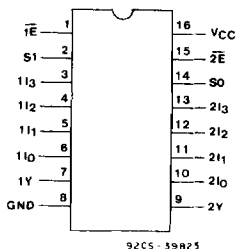
\*For up to 4 outputs per device; add  $\pm 25$  mA for each additional output.

**RECOMMENDED OPERATING CONDITIONS:**

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range, $V_{CC}$ *: (For $T_A =$ Full Package-Temperature Range) AC Types ACT Types	1.5 4.5	5.5 5.5	V
DC Input or Output Voltage, $V_I, V_O$	0	$V_{CC}$	V
Operating Temperature, $T_A$	-55	+125	$^\circ\text{C}$
Input Rise and Fall Slew Rate, $dt/dv$ at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)	0 0 0	50 20 10	ns/V ns/V ns/V

\*Unless otherwise specified, all voltages are referenced to ground.



92CS-59825

**TERMINAL ASSIGNMENT**

STATIC ELECTRICAL CHARACTERISTICS: AC Series

CHARACTERISTICS	TEST CONDITIONS		V <sub>CC</sub> (V)	AMBIENT TEMPERATURE (T <sub>A</sub> ) - °C						UNITS	
				+25		-40 to +85		-55 to +125			
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
High-Level Input Voltage V <sub>IH</sub>			1.5	1.2	—	1.2	—	1.2	—	V	
			3	2.1	—	2.1	—	2.1	—		
			5.5	3.85	—	3.85	—	3.85	—		
Low-Level Input Voltage V <sub>IL</sub>			1.5	—	0.3	—	0.3	—	0.3	V	
			3	—	0.9	—	0.9	—	0.9		
			5.5	—	1.65	—	1.65	—	1.65		
High-Level Output Voltage V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	#, *	-0.05	1.5	1.4	—	1.4	—	1.4	—	V
			-0.05	3	2.9	—	2.9	—	2.9	—	
			-0.05	4.5	4.4	—	4.4	—	4.4	—	
			-4	3	2.58	—	2.48	—	2.4	—	
			-24	4.5	3.94	—	3.8	—	3.7	—	
			-75	5.5	—	—	3.85	—	—	—	
Low-Level Output Voltage V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	#, *	0.05	1.5	—	0.1	—	0.1	—	0.1	V
			0.05	3	—	0.1	—	0.1	—	0.1	
			0.05	4.5	—	0.1	—	0.1	—	0.1	
			12	3	—	0.36	—	0.44	—	0.5	
			24	4.5	—	0.36	—	0.44	—	0.5	
			75	5.5	—	—	—	1.65	—	—	
Input Leakage Current I <sub>I</sub>	V <sub>CC</sub> or GND		5.5	—	±0.1	—	±1	—	±1	μA	
Quiescent Supply Current, MSI I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	—	8	—	80	—	160	μA	

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

# CD54/74AC153

## CD54/74ACT153

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

CHARACTERISTICS	TEST CONDITIONS		V <sub>CC</sub> (V)	AMBIENT TEMPERATURE (T <sub>A</sub> ) - °C						UNITS	
				+25		-40 to +85		-55 to +125			
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V <sub>IH</sub>		4.5 to 5.5	2	—	2	—	2	—	V	
Low-Level Input Voltage	V <sub>IL</sub>		4.5 to 5.5	—	0.8	—	0.8	—	0.8	V	
High-Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub> #,*	-0.05	4.5	4.4	—	4.4	—	4.4	—	V
			-24	4.5	3.94	—	3.8	—	3.7	—	
			-75	5.5	—	—	3.85	—	—	—	
			-50	5.5	—	—	—	—	3.85	—	
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub> #,*	0.05	4.5	—	0.1	—	0.1	—	0.1	V
			24	4.5	—	0.36	—	0.44	—	0.5	
			75	5.5	—	—	—	1.65	—	—	
			50	5.5	—	—	—	—	—	1.65	
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> or GND	5.5	—	±0.1	—	±1	—	±1	μA	
Quiescent Supply Current, MSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	—	8	—	80	—	160	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High 1 Unit Load	ΔI <sub>CC</sub>	V <sub>CC</sub> -2.1	4.5 to 5.5	—	2.4	—	2.8	—	3	mA	

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOADS*
S0, S1, nI <sub>0</sub> , nI <sub>1</sub> nE	1 0.47

\*Unit load is ΔI<sub>CC</sub> limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

# CD54/74AC153

## CD54/74ACT153

SWITCHING CHARACTERISTICS: AC Series;  $t_r, t_f = 3 \text{ ns}$ ,  $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	$V_{CC}$ (V)	AMBIENT TEMPERATURE ( $T_A$ ) - °C				UNITS
			-40 to +85		-55 to +125		
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: S0, S1, to Y	$t_{PLH}$	1.5	—	227	—	250	ns
	$t_{PHL}$	3.3*	7.2	25.5	7	28	
		5†	5.2	18.2	5	20	
nl to Y	$t_{PLH}$	1.5	—	151	—	166	ns
	$t_{PHL}$	3.3	4.8	16.9	4.7	18.6	
		5	3.4	12.1	3.3	13.3	
$\overline{nE}$ to Y	$t_{PLH}$	1.5	—	134	—	148	ns
	$t_{PHL}$	3.3	4.3	15	4.1	16.5	
		5	3.1	10.7	3	11.8	
Power Dissipation Capacitance	$C_{PD}\S$	—	93 Typ.		93 Typ.		pF
Input Capacitance	$C_i$	—	—	10	—	10	pF

\*3.3 V: min. is @ 3.6 V  
max. is @ 3 V

†5 V: min. is @ 5.5 V  
max. is @ 4.5 V

§ $C_{PD}$  is used to determine the dynamic power consumption, per multiplexer.

$$P_D = V_{CC}^2 f_i (C_{PD} + C_L) \text{ where } f_i = \text{input frequency}$$

$C_L = \text{output load capacitance}$   
 $V_{CC} = \text{supply voltage.}$

SWITCHING CHARACTERISTICS: ACT Series;  $t_r, t_f = 3 \text{ ns}$ ,  $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	$V_{CC}$ (V)	AMBIENT TEMPERATURE ( $T_A$ ) - °C				UNITS
			-40 to +85		-55 to +125		
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: S0, S1, to Y	$t_{PLH}$	5†	5.7	20	5.5	22	ns
	$t_{PHL}$						
nl to Y	$t_{PLH}$	5	4.6	16.4	4.5	18	ns
	$t_{PHL}$						
$\overline{nE}$ to Y	$t_{PLH}$	5	3.2	11.5	3.2	12.6	ns
	$t_{PHL}$						
Power Dissipation Capacitance	$C_{PD}\S$	—	93 Typ.		93 Typ.		pF
Input Capacitance	$C_i$	—	—	10	—	10	pF

†5 V: min. is @ 5.5 V  
max. is @ 4.5 V

§ $C_{PD}$  is used to determine the dynamic power consumption, per multiplexer.

$$P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC} \text{ where } f_i = \text{input frequency}$$

$C_L = \text{output load capacitance}$   
 $V_{CC} = \text{supply voltage.}$

# CD54/74AC153 CD54/74ACT153

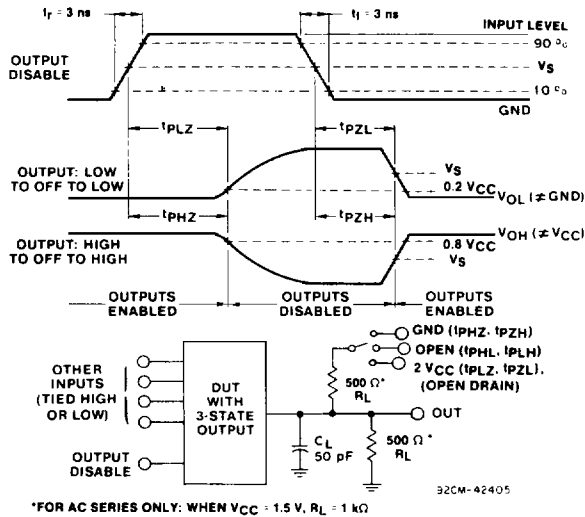


Fig. 1 - Three-state propagation delay waveforms and test circuit.

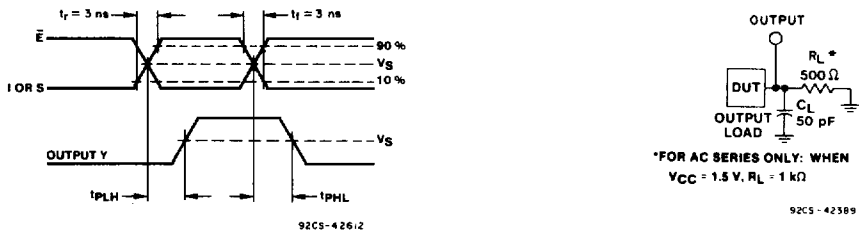


Fig. 2 - Propagation delay times and test circuit.

	CD54/74AC	CD54/74ACT
Input Level	$V_{CC}$	3 V
Input Switching Voltage, $V_S$	$0.5 V_{CC}$	1.5 V
Output Switching Voltage, $V_S$	$0.5 V_{CC}$	$0.5 V_{CC}$